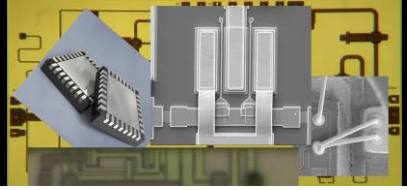
TMC655D
DC-75 GHz
Distributed Amplifier



mmTRON
Unleashing the mmWave Frontier

Product Features

- RF frequency: DC to 75 GHz
- Linear Gain: 17 dB
- Noise Figure: 7 dB
- Die Size: X=2.6 mm, Y=1.45 mm, Z=0.05mm
- DC Power: 5 VDC, 270 mA

Application

- Point-to-Point Radios and VSATs
- Test instrumentation
- Fiber Optics
- Military, EW and Space

Product Description

The TMC655D GaAs PHEMT Distributed amplifier is a broadband high gain device with positive gain slope, designed for use in Radios, Test instrumentation, Military, EW and Space applications. The TMC655D is a 50 Ω matched design providing 7dB of noise figure, offers excellent return loss at low-end for optical instrumentation, interface to photodiodes, and eliminates the need for RF port matching. Both bond pad and backside metallization are Au-based that is compatible with ribbon and wedge bonding and high conductivity epoxy and eutectic die attach methods.

Electrical Performance : **Vdd = 5 V, Vgg = -0.4 V, TA = 25 °C, F = 70 GHz**				
	min	**Typ**	**Max**	**Units**
Frequency	DC		75	GHz
Gain		17		dB
P1dB		19		dBm
Psat		20		dBm
Noise Figure		7		dB
OIP3		27		dBm
Bias Voltage		5		V
Bias Current		265		mA

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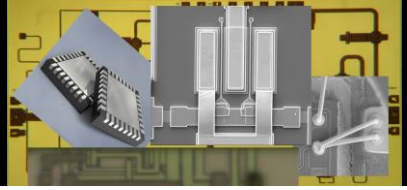
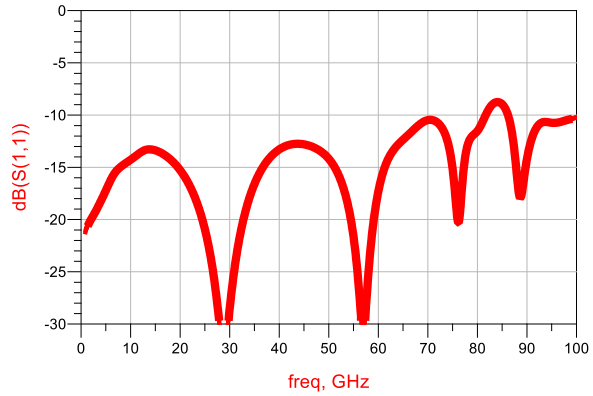
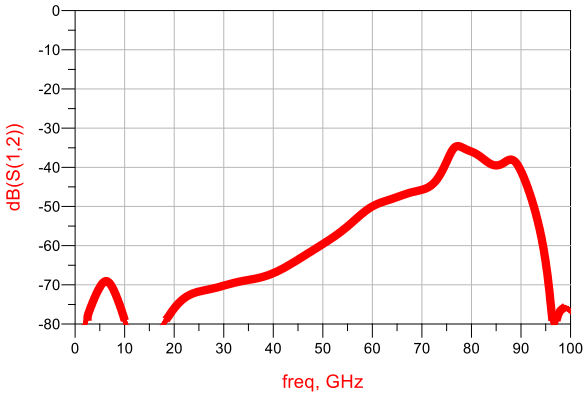


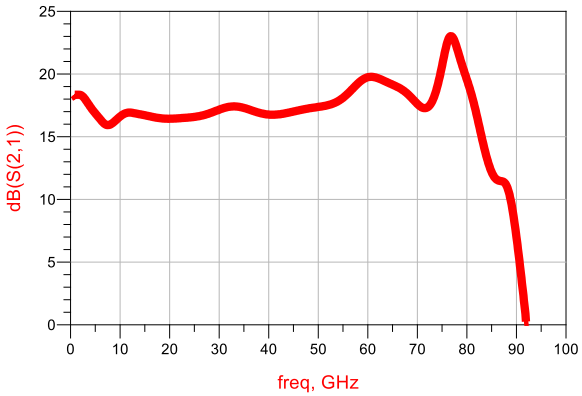
TMC655 Input Return Loss



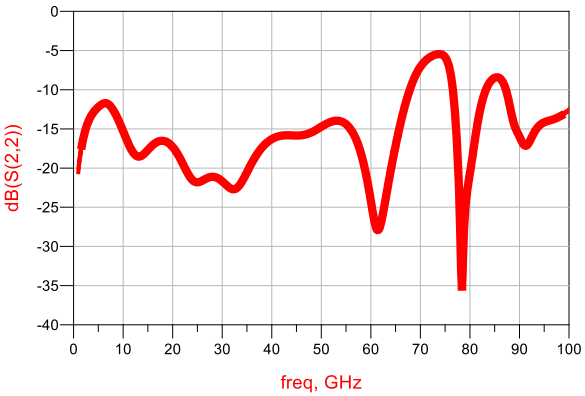
TMC655 Reverse Isolation



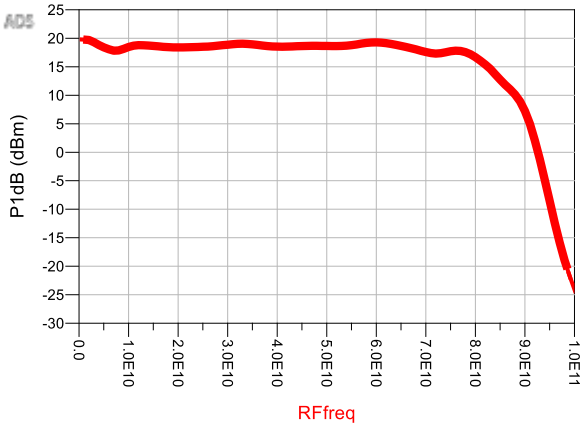
TMC655 Gain



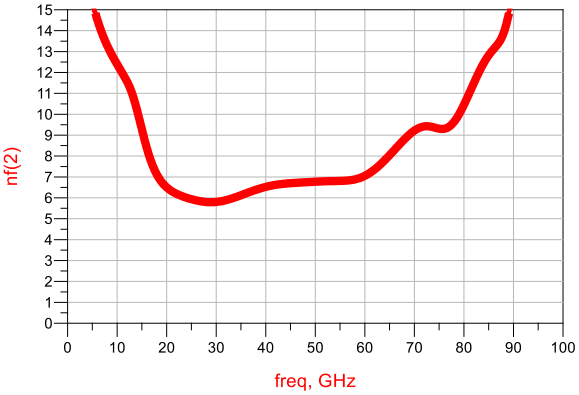
TMC655 Output Return Loss



TMC655 P1dB



TMC655 Noise Figure



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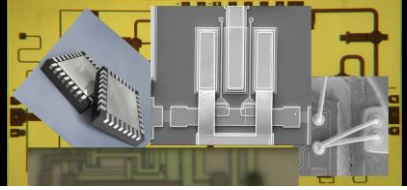
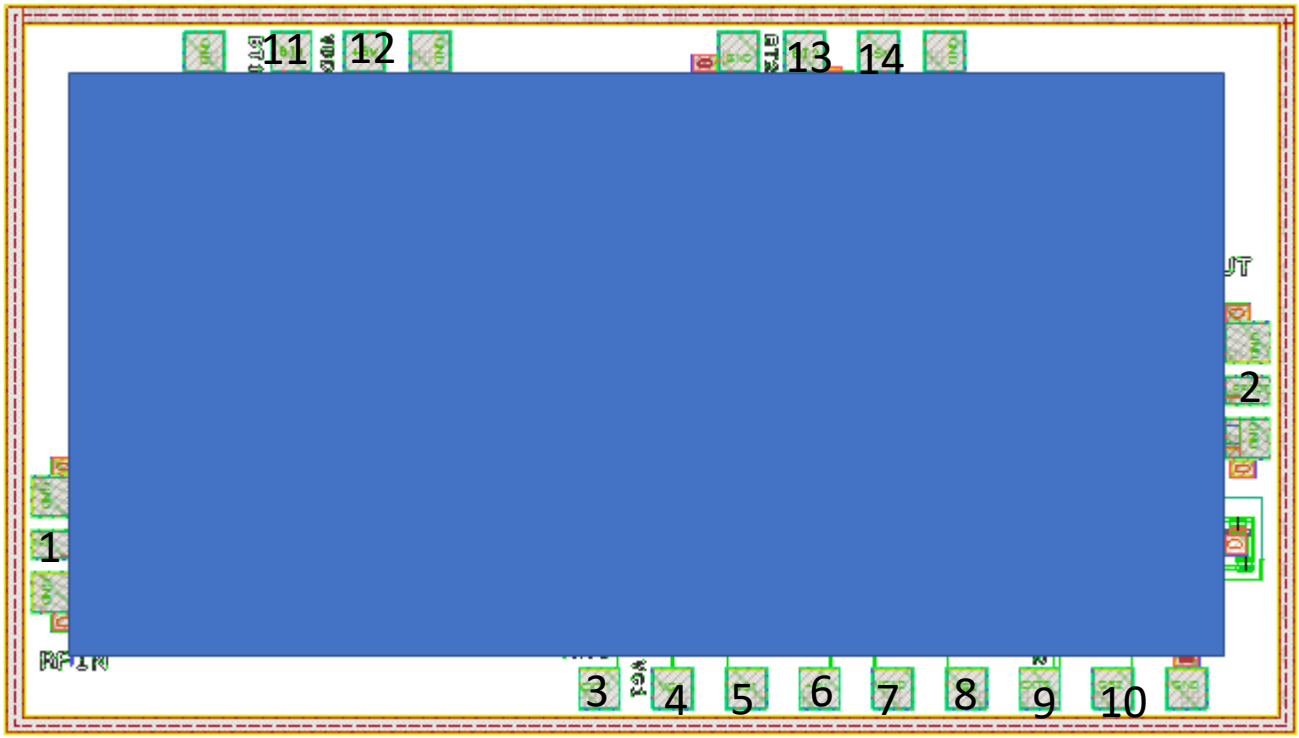
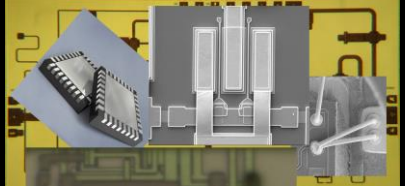
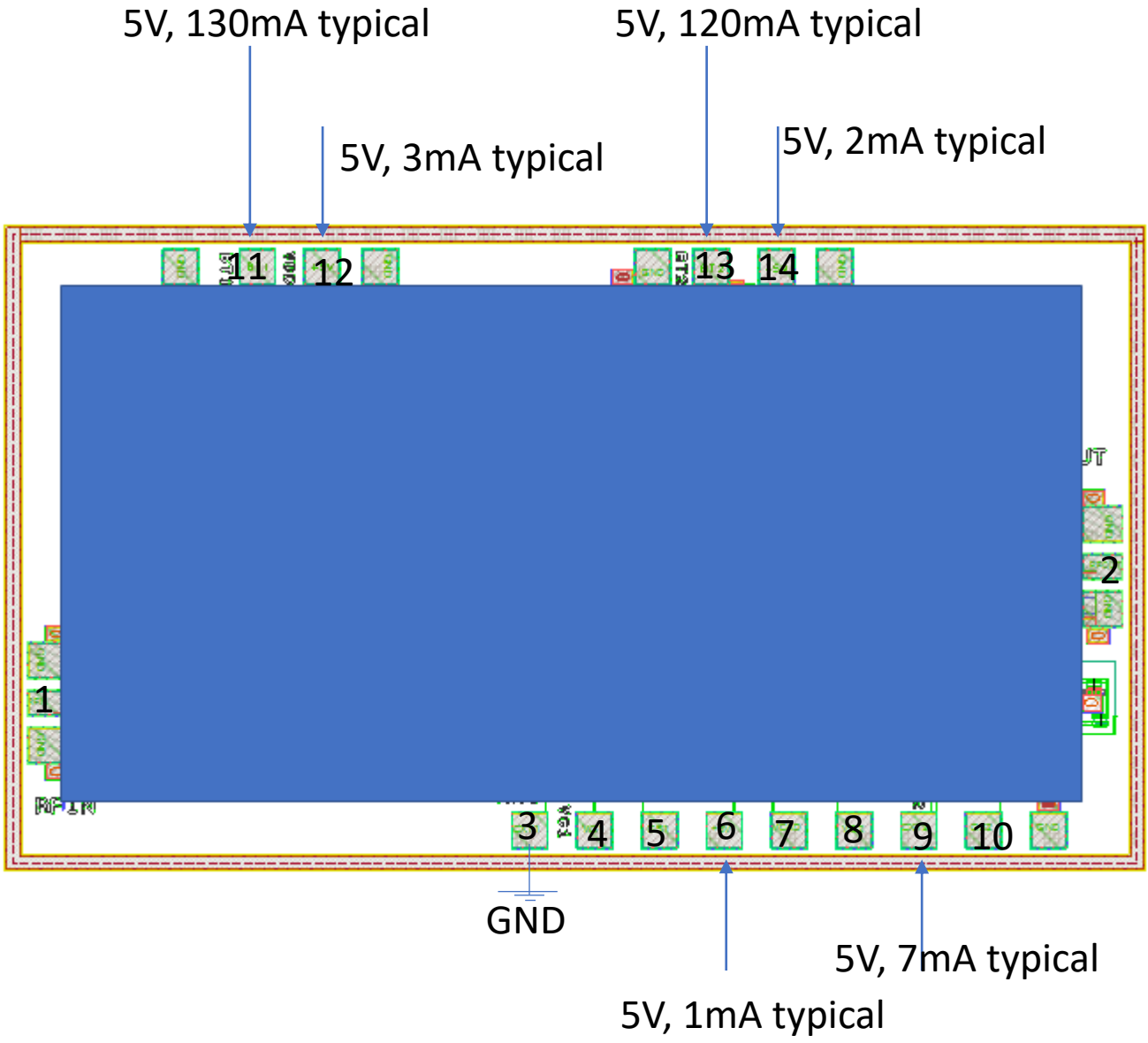
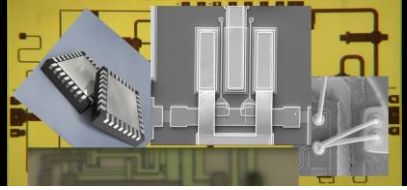




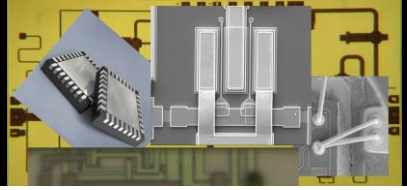
Pad #	Function	Connection
1	RF INPUT	DC-Coupled
2	RF OUTPUT	DC-Coupled
3	CXT1	Short wire bond to GND
4	VG1	-0.4V (adjust to achieve desired currents), draws -1mA
5	GS1	
6	VDD	5V, draws 1mA
7	VCAD	Short wire bond to 100pF+1nF Cap to GND, adjust for the low frequency end
8	VG2	
9	CXT2	5V, draws 8mA
10	GS2	
11	BT1	5V, draws 130mA
12	VDD	5V, draws 3mA
13	BT2	5V, draws 120mA
14	VDD	5V, draws 2mA




5V, 130mA typical
5V, 120mA typical
5V, 3mA typical
5V, 2mA typical
11
12
13
14
1
2
3
4
5
6
7
8
9
10
GND
5V, 7mA typical
5V, 1mA typical



Absolute max Idd:
Absolute max Vdd :8V
Absolute max Vg2 (relative to GND and relative to Vdd) : -1V
Absolute max Vg1 (relative to GND) : -1V
Can we apply Idd through the on-chip termination? No
If so, what is the maximum current? Which bonding pad to use?
Can we apply Idd through an external bias tee on the RF OUTPUT?
If so, what is the maximum current?
Are these depletion mode devices? Yes
What is the pinch-off voltage of Vg1? -0.7V
If we apply Vg1=-0.4V and Vdd=5V through an external bias tee, what is the expected Idd? Is it 230mA or 270mA?
Please provide pin functionality descriptions for all bonding pads, especially CXT1, GS1, VCAD, CXT2, GS2, BT1, BT2?
Are there any bonding pads not needed for powering the device but which require external bypass capacitors?
What is your recommended power-up procedure?



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